



MPSA42/43

NPN SILICON TRANSISTOR

HIGH VOLTAGE TRANSISTOR

DESCRIPTION

The UTC MPSA42/43 are high voltage transistors, designed for telephone switch and high voltage switch.

FEATURES

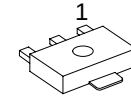
*Collector-Emitter voltage:

$V_{CE0}=300V$ (UTC MPSA42)

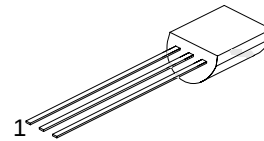
$V_{CE0}=200V$ (UTC MPSA43)

*High current gain

*Complement to UTC MPSA92/93



SOT-89



TO-92

*Pb-free plating product number: MPSA42L
MPSA43L

ORDERING INFORMATION

Order Number		Package	Pin Assignment			Packing
Normal	Lead Free Plating		1	2	3	
MPSA42-AB3-R	MPSA42L-AB3-R	SOT-89	B	C	E	Tape Reel
MPSA42-T92-B	MPSA42L-T92-B	TO-92	E	B	C	Tape Box
MPSA42-T92-K	MPSA42L-T92-K	TO-92	E	B	C	Bulk
MPSA43-AB3-R	MPSA43L-AB3-R	SOT-89	B	C	E	Tape Reel
MPSA43-T92-B	MPSA43L-T92-B	TO-92	E	B	C	Tape Box
MPSA43-T92-K	MPSA43L-T92-K	TO-92	E	B	C	Bulk

MPSA42L-AB3-R

(1)Packing Type

(2)Package Type

(3)Lead Plating

(1) B: Tape Box, K: Bulk, R: Tape Reel

(2) AB3: SOT-89, T92: TO-92

(3) L: Lead Free Plating, Blank: Pb/Sn

■ ABSOLUTE MAXIMUM RATINGS (Operating temperature range applies unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Collector-Base Voltage	MPSA42	V_{CBO}	300	V
	MPSA43		200	V
Collector-Emitter Voltage	MPSA42	V_{CEO}	300	V
	MPSA43		200	V
Emitter-Base Voltage		V_{EBO}	6	V
Collector Current		I_C	500	mA
Collector Dissipation ($T_a=25^\circ\text{C}$)	SOT-89	P_C	500	mW
	TO-92		625	mW
Junction Temperature		T_J	150	$^\circ\text{C}$
Storage Temperature		T_{STG}	-55 ~ +150	$^\circ\text{C}$

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ ELECTRICAL CHARACTERISTICS ($T_J=25^\circ\text{C}$, unless otherwise specified)

PARAMETER		SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector-Base Breakdown Voltage	MPSA42	BV _{CBO}	I _C =100μA, I _E =0	300			V
	MPSA43			200			
Collector-Emitter Breakdown Voltage	MPSA42	BV _{CEO}	I _C =1mA, I _B =0	300			V
	MPSA43			200			
Emitter-Base Breakdown Voltage		BV _{EBO}	I _E =100μA, I _C =0	6			V
Collector Cut-Off Current	MPSA42	I _{CBO}	V _{CB} =200V, I _E =0			100	nA
	MPSA43		V _{CB} =160V, I _E =0			100	
Emitter Cut-Off Current	MPSA42	I _{EBO}	V _{BE} =6V, I _C =0			100	nA
	MPSA43		V _{BE} =4V, I _C =0			100	
DC Current Gain		h _{FE}	V _{CE} =10V, I _C =1mA	80		300	
			V _{CE} =10V, I _C =10mA	80			
			V _{CE} =10V, I _C =30mA	80			
Collector-Emitter Saturation Voltage		V _{CE(SAT)}	I _C =20mA, I _B =2mA			0.2	V
Base-Emitter Saturation Voltage		V _{BE(SAT)}	I _C =20mA, I _B =2mA			0.90	V
Current Gain Bandwidth Product		f _T	V _{CE} =20V, I _C =10mA, f=100MHz	50			MHz
Collector Base Capacitance	MPSA42	C _{cb}	V _{CB} =20V, I _E =0 f=1MHz			3	pF
	MPSA43					4	pF

TYPICAL CHARACTERISTICS

Fig.1 DC Current Gain

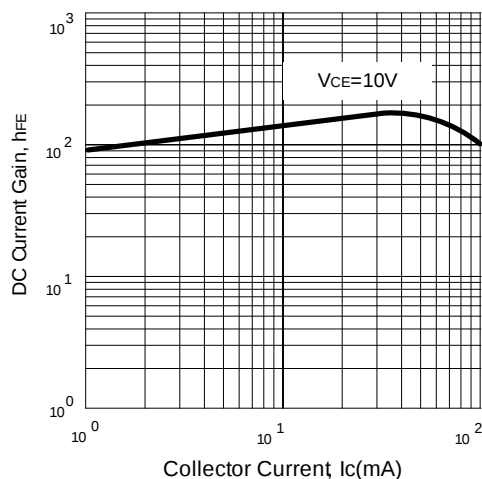


Fig.2 Saturation Voltage

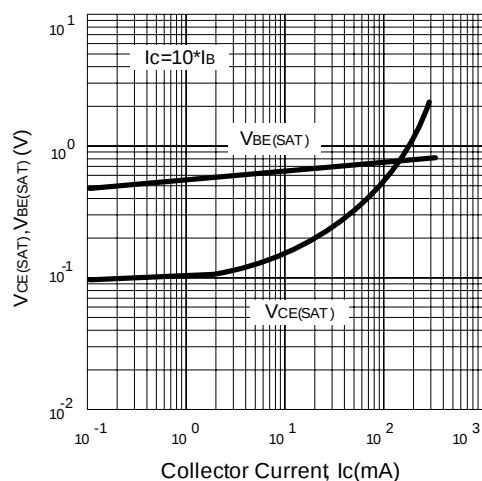


Fig.3 Capacitance

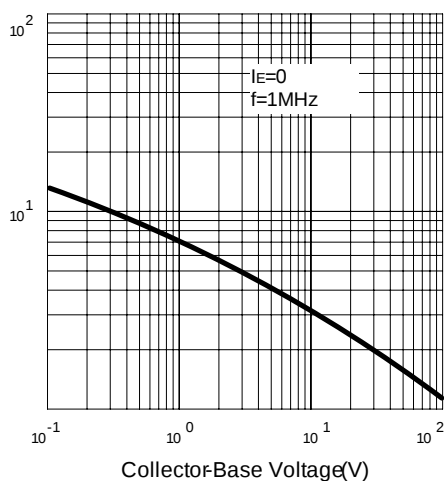
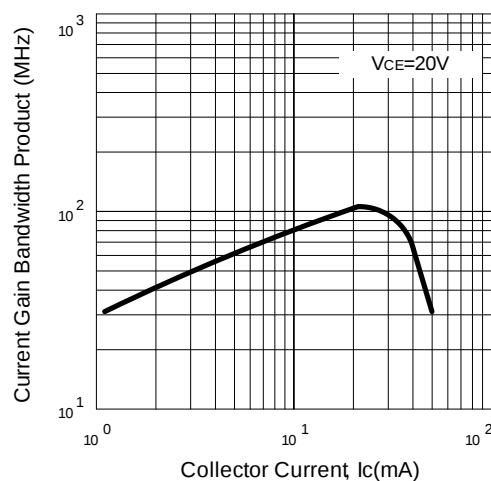


Fig.4 Current Gain Bandwidth Product



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